

Solid State Power Amplifier Module 2000 to 6000MHz, 300 Watts MODEL BME2969-300

Features:

- Highest Power Density to Footprint Ratio
- Ultra Wideband Operation
- Highest Efficiency Over the Entire Bandwidth
- Rugged and Reliable
- Extreme Temperature Range Usage
- RF Output Coupled Sample Port
- Internal DC to DC Converters
- Suitable Building Block for Rack Mounted Systems
- Maintains Output Power with Real-World Load Conditions



Performance Specifications

Frequency Range:
Saturated Power Output (Psat):
Output Power into 2.0:1 VSWR:
RF Input Range:
RF input Overdrive:
DC Bias:

2000 to 6000 MHz
300 Watts
200 Watts Min
-10 to 0dBm Typical
+10 dBm Max.
AB Linear

Modulation Format:
 Multi-tone, CW, AM, FM, Pulse

Input VSWR:
 Output Load VSWR:
 Harmonic (In Band 2nd/3rd):
 IM Products (4 Tones):
 Spurious:
 2.0:1 Typical
 <-20 dBc Typical
 <-60 dBc

 Stability: Open/Short Tested
 Built in Test: Composite Fault Indication RS-422 (Over Temp, Over

Current)

• Fwd./Rev. Sample

Analog Voltage

Noise Power Output:

 Biased
 Quieted
 -70dBm/Hz Typical
 -150dBm/Hz Typical

Summary Fault Indication: 3.3V RS-422
PA Blanking Enable/Disable: 3.3V RS-422 (<5μS)
DC Input: 18-32VDC
DC Power @ 28V: 1800W Typical
Efficiency (DC to RF): 18% Typical
RF Connectors:

RF Input: SMA (1X)
RF Output: SC (1X)
RF Out Coupled Sample: SMA (1X)

Arriva Connector: SMA (1X)

Interface Connector: D-Subminiature (1X)
 DC Power Connector D-Subminiature (1X)
 Operating Temperature: -40 to +70°C Baseplate (External heatsink required)

Altitude

Relative Humidity

Environmental:

Size:

• Weight:

18% Typical

SMA (1X)
SC (1X)
SMA (1X)
D-Subminiature (1X)
D-Subminiature (1X)
-40 to +70°C Baseplate
(External heatsink required)
up to 50kft

100% Condensing Shock/Vibration MIL-STD-810F 15.25" x 7" x 2.67" 17 lbs. Max

COMTECH PST proudly introduces the highest power density solid state RF modules available in the marketplace today. Comtech's latest development expands on its proven innovative integrated RF GaN Power Amplifier designs by further increasing the RF power density, while improving overall operating efficiency. Consistent with its planned technology development roadmap, Comtech is leading the field with the latest in GaN-based RF device performance and advanced amplifier development. These highly integrated designs are ideal for use in communication, electronic warfare, and radar transmitter systems where space, cooling, and power are limited. Applications include ground (mobile or fixed), surface, and airborne platforms.

Contact Comtech PST with your specific requirements for a customized solution.